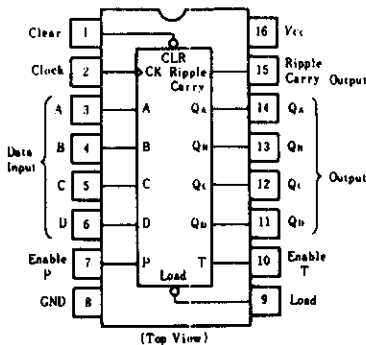


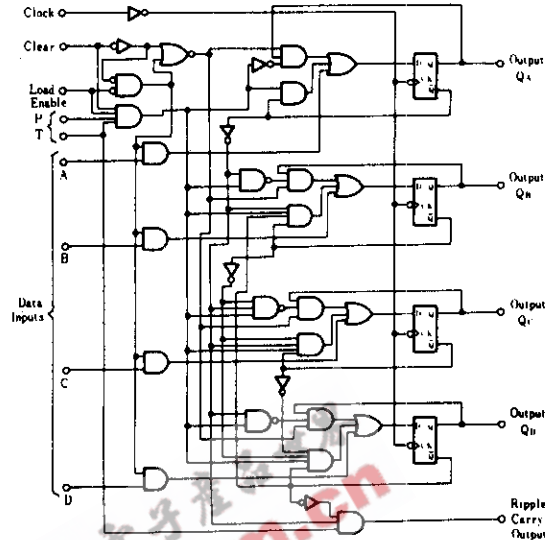
HD74LS162A • Synchronous Decade Counters (synchronous clear)

This synchronous decade counter features an internal carry look-ahead for application in high-speed counting designs. Synchronous operation is provided by having all flip-flops clocked simultaneously so that the outputs change coincident with each other when so instructed by the count-enable inputs and internal gating. This mode of operation eliminates the output counting spikes that are normally associated with asynchronous (ripple clock) counters. A buffered clock input triggers the four flip-flops on the rising (positive-going) edge of the clock input waveform. This counter is fully programmable; that is, the outputs may be preset to either level. As presetting is synchronous, setting up a low level at the load input disables the counter and causes the outputs to agree with the setup data after the next clock pulse regardless of the levels of the enable inputs. Low-to-high transitions at the load input should be avoided when the clock is low if the enable inputs are high at or before the transition. The clear function is synchronous and a low level at the clear input sets all four of the flip-flop outputs low after the next clock pulse, regardless of the levels of the enable inputs. This synchronous clear allows the count length to be modified easily as decoding the maximum count desired can be accomplished with one external NAND gate. The gate output is connected to the clear input to synchronously clear the counter to LLLL. Low-to-high transitions at the clear input should be avoided when the clock is low if the enable and load inputs are high at or before the transition. The carry look-ahead circuitry provides for cascading counters for n-bit synchronous applications without additional gating. Instrumental in accomplishing this function are two count-enable inputs and a ripple carry output. Both count-enable inputs (P and T) must be high to count, and input T is fed forward to enable the ripple carry output. The ripple carry output thus enabled will produce a high-level output pulse with a duration approximately equal to the high-level portion of the Q_A output. This high-level overflow ripple carry pulse can be used to enable successive cascaded stages. High-to-low-level transitions at the enable P or T inputs should occur only when the clock input is high.

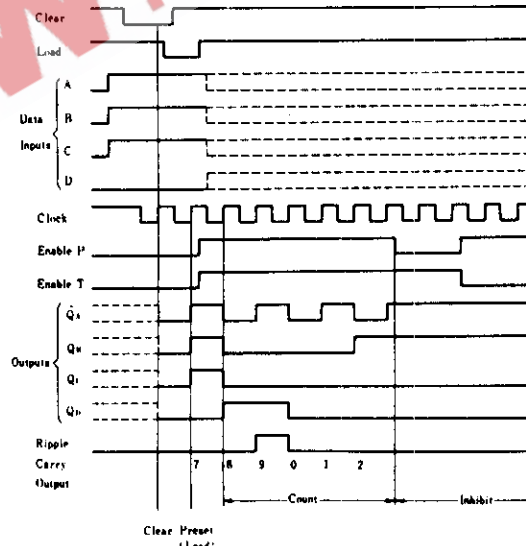
■ PIN ARRANGEMENT



■ BLOCK DIAGRAM



■ TYPICAL CLEAR, PRESET, AND INHIBIT SEQUENCE

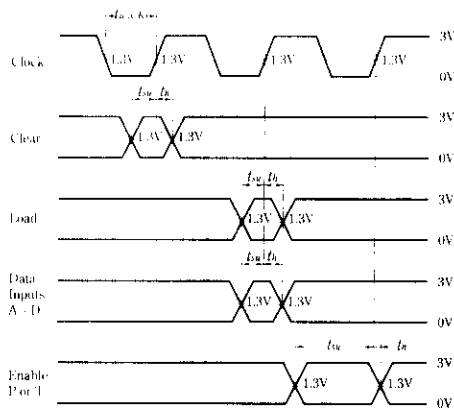


■ RECOMMENDED OPERATING CONDITIONS

| Item | Symbol | min | typ | max | Unit |
|-------------------|-------------|-----|-----|-----|------|
| Clock frequency | f_{clock} | 0 | — | 25 | MHz |
| Clock pulse width | $t_w(CK)$ | 25 | — | — | ns |
| Clear pulse width | $t_w(CLR)$ | 20 | — | — | ns |
| Setup time | A, B, C, D | 20 | — | — | ns |
| | Enable P, T | 20 | — | — | ns |
| | Load | 20 | — | — | ns |
| | Clear | 20 | — | — | ns |
| Hold time | t_h | 3 | — | — | ns |

HD74LS162A

■TIMING DEFINITION



■ELECTRICAL CHARACTERISTICS (T_a = -20 ~ +75°C)

| Item | Symbol | Test Conditions | min | typ* | max | Unit | |
|------------------------------|--|---|------|------|------|------|----|
| Input voltage | V _{IH} | | 2.0 | — | — | V | |
| | V _{IL} | | — | — | 0.8 | V | |
| Output voltage | V _{OH} | V _{CC} = 4.75V, V _{IH} = 2V, V _{IL} = 0.8V, I _{OH} = -400μA | 2.7 | — | — | V | |
| | V _{OL} | V _{CC} = 4.75V, V _{IH} = 2V, I _{OL} = 4mA | — | — | 0.4 | V | |
| | | V _{CC} = 4.75V, V _{IH} = 2V, I _{OL} = 8mA | — | — | 0.5 | | |
| Input current | Data, Enable P | V _{CC} = 5.25V, V _I = 2.7V | — | — | 20 | μA | |
| | Load, Clock, Enable T | | — | — | 40 | | |
| | Clear | | — | — | 40 | | |
| | Data, Enable P | | — | — | -0.4 | | mA |
| | Load, Clock, Enable T | | — | — | -0.8 | | |
| Clear | — | — | -0.8 | | | | |
| Data, Enable P | V _{CC} = 5.25V, V _I = 7V | — | — | 0.1 | mA | | |
| Load, Clock, Enable T | | — | — | 0.2 | | | |
| Clear | | — | — | 0.2 | | | |
| Short-circuit output current | I _{OS} | V _{CC} = 5.25V | -20 | — | 100 | mA | |
| Supply current** | I _{CCH} | V _{CC} = 5.25V | — | 18 | 31 | mA | |
| | I _{CLL} | V _{CC} = 5.25V | — | 19 | 32 | mA | |
| Input clamp voltage | V _{IK} | V _{CC} = 4.75V, I _{IK} = 18mA | — | — | 1.5 | V | |

* V_{CC} = 5V, T_a = 25°C

** I_{CCH} is measured with the load input high, then again with the load input low, with all other inputs high and all outputs open. I_{CLL} is measured with the clock input high, then again with the clock input low, with all other inputs low and all outputs open.

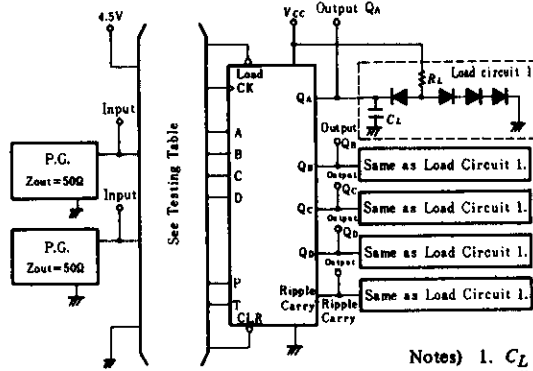
■SWITCHING CHARACTERISTICS (V_{CC} = 5V, T_a = 25°C)

| Item | Symbol | Inputs | Outputs | Test Conditions | min | typ | max | Unit | |
|-------------------------|------------------|---------------------------------|---------------------------------|---|--------------|-----|-----|------|----|
| Maximum clock frequency | f _{max} | Clock | Q _A ~ Q _D | C _L = 15pF, R _L = 2kΩ | 25 | 32 | — | MHz | |
| Propagation delay time | t _{PLH} | Clock | Ripple | | — | 20 | 35 | ns | |
| | | | Carry | | — | 18 | 35 | ns | |
| | t _{PLH} | Clock | Q _A ~ Q _D | | (Load = "H") | — | 13 | 24 | ns |
| | | | | | (Load = "L") | — | 18 | 27 | ns |
| | t _{PHL} | Clock | Q _A ~ Q _D | | (Load = "H") | — | 13 | 24 | ns |
| | | | | | (Load = "L") | — | 18 | 27 | ns |
| | t _{PLH} | Enable T | Ripple | | Carry | — | 9 | 14 | ns |
| | | | | | | — | 9 | 14 | ns |
| t _{PHL} | Clear | Q _A ~ Q _D | — | | 20 | 28 | ns | | |

HD74LS162A

TESTING METHOD

1) Test Circuit



- Notes) 1. C_L includes probe and jig capacitance.
2. All diodes are 1S2074 (H)

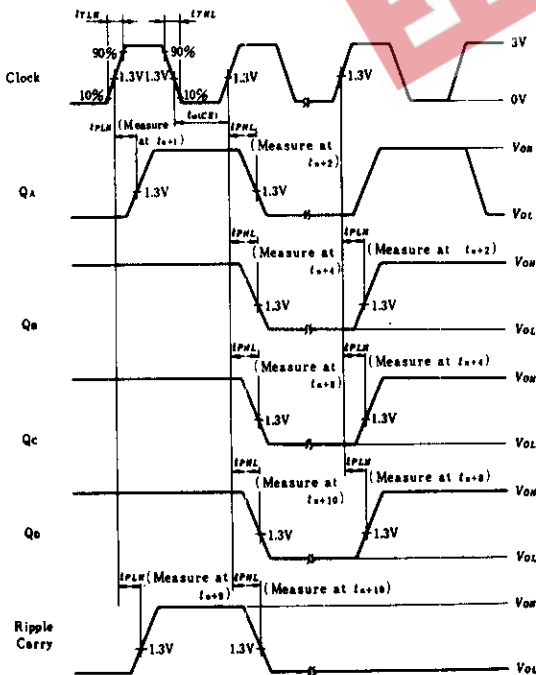
2) Testing Table

| Item | From input to output | Inputs | | | | | | | | | | Outputs | | | | |
|-----------|-----------------------|--------|------|--------|------|-------|------|------|------|------|------|---------|-----|-----|--------------|-----|
| | | Clear | Load | Enable | | Clock | Data | | | | QA | QB | QC | QD | Ripple Carry | |
| | | | | P | T | | A | B | C | D | | | | | | |
| f_{max} | | 4.5V | 4.5V | 4.5V | 4.5V | IN | GND | GND | GND | GND | GND | OUT | OUT | OUT | OUT | OUT |
| t_{PLH} | CK→Ripple Carry | 4.5V | 4.5V | 4.5V | 4.5V | IN | GND | GND | GND | GND | GND | — | — | — | — | OUT |
| | CK→Q | 4.5V | 4.5V | 4.5V | 4.5V | IN | GND | GND | GND | GND | GND | OUT | OUT | OUT | OUT | — |
| t_{PHL} | CK→Q | 4.5V | GND | GND | GND | IN | IN* | IN* | IN* | IN* | IN* | OUT | OUT | OUT | OUT | — |
| | Enable T→Ripple Carry | 4.5V | GND | 4.5V | IN | IN** | 4.5V | GND | GND | 4.5V | 4.5V | — | — | — | — | OUT |
| | Clear→Q | IN | GND | GND | GND | IN** | 4.5V | 4.5V | 4.5V | 4.5V | 4.5V | OUT | OUT | OUT | OUT | — |

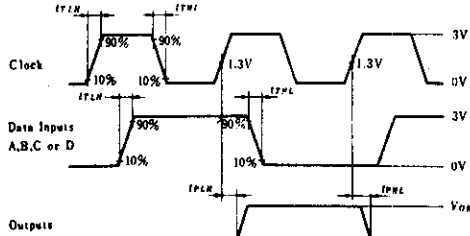
* Measuring outputs correspond to this condition, each outputs (Q_A , Q_B , Q_C , and Q_D) must not be over the following rate, "H", "L", "L", and "H".

** For initialized

3) Waveform-1 f_{max} , t_{PLH} , t_{PHL} (Clock→Q, Ripple Carry)

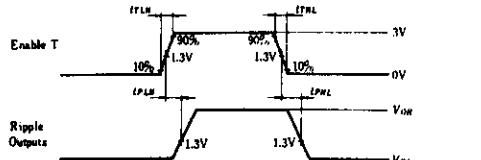


Waveform-2 t_{PLH} , t_{PHL} (Clock→Q)



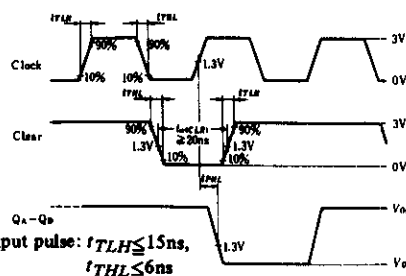
Notes) Input pulse: $t_{TLH} \leq 15ns$, $t_{THL} \leq 6ns$, Clock input: $PRR = 1MHz$, duty cycle 50%, Data input: $PRR = 500kHz$, duty cycle 50%

Waveform-3 t_{PLH} , t_{PHL} (Enable T→Ripple Carry)



Note) Input pulse: $t_{TLH} \leq 15ns$, $t_{THL} \leq 6ns$, $PRR = 1MHz$

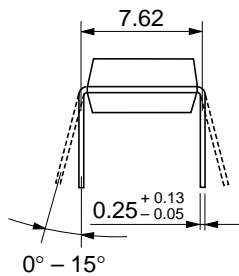
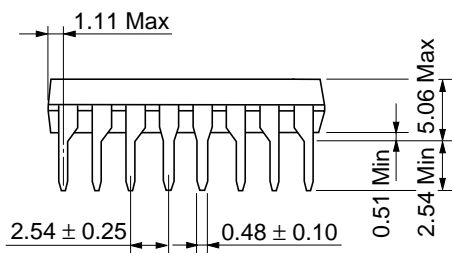
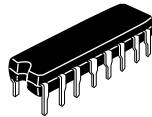
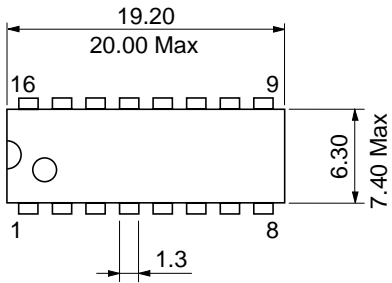
Waveform-4 t_{PHL} (Clear→Q)



Note) Input pulse: $t_{TLH} \leq 15ns$, $t_{THL} \leq 6ns$

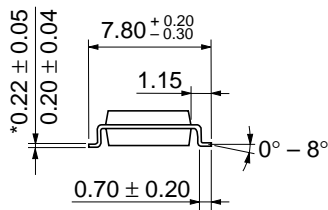
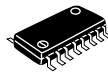
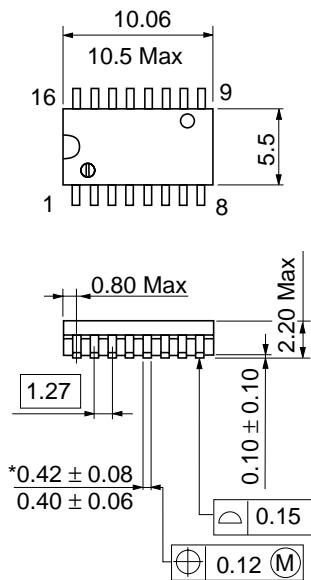
- Notes) 1. Clock input pulse; $t_{TLH} \leq 15ns$, $t_{THL} \leq 6ns$, $PRR = 1MHz$, duty cycle=50% and; for f_{max} , $t_{TLH} = t_{THL} \leq 2.5ns$.
2. t_n is reference bit time when all outputs are low.

Unit: mm



| | |
|--------------------------|----------|
| Hitachi Code | DP-16 |
| JEDEC | Conforms |
| EIAJ | Conforms |
| Weight (reference value) | 1.07 g |

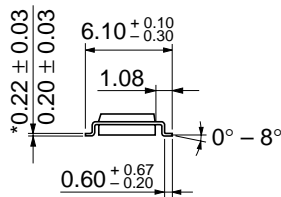
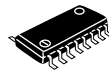
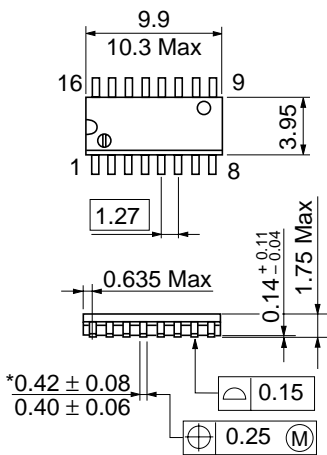
Unit: mm



| | |
|--------------------------|----------|
| Hitachi Code | FP-16DA |
| JEDEC | — |
| EIAJ | Conforms |
| Weight (reference value) | 0.24 g |

*Dimension including the plating thickness
Base material dimension

Unit: mm



*Dimension including the plating thickness
Base material dimension

| | |
|--------------------------|----------|
| Hitachi Code | FP-16DN |
| JEDEC | Conforms |
| EIAJ | Conforms |
| Weight (reference value) | 0.15 g |

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